NSN 5961-01-081-0421

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Fiig: A110a0



View Online at https://aerobasegroup.com/nsn/5961-01-081-0421 **Inclosure Material:** Ceramic or plastic **Overall Length:** 26.0 millimeters **Overall Height:** 16.6 millimeters **Overall Width:** 26.0 millimeters **Mounting Facility Quantity: Internal Configuration:** Junction contact **Mounting Method:** Threaded stud **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 30.0 collector to base voltage/static/emitter open and 35.0 collector to emitter reverse voltage and 25.0 collector to emitter voltage/static/base open and 3.0 emitter to base voltage, static, collector open **Current Rating Per Characteristic:** 150.00 milliamperes source cutoff current **Power Rating Per Characteristic:** 3.5 watts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Ceramic case of bfr94a contains beryllium oxide - handle and dispose iaw hazmat procedures; junction pattern arrangement: npn **Terminal Type And Quantity:** 4 ribbon Shelf Life: N/a **Unit Of Measure: Demilitarization:** No